MC74VHC1GT125

Noninverting Buffer / CMOS Logic Level Shifter

with LSTTL–Compatible Inputs

The MC74VHC1GT125 is a single gate noninverting buffer fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

The MC74VHC1GT125 requires the 3–state control input ($\overline{OE}$) to be set High to place the output into the high impedance state.

The device input is compatible with TTL–type input thresholds and the output has a full 5 V CMOS level output swing. The input protection circuitry on this device allows overvoltage tolerance on the input, allowing the device to be used as a logic–level translator from 3.0 V CMOS logic to 5.0 V CMOS Logic or from 1.8 V CMOS logic to 3.0 V CMOS Logic while operating at the high–voltage power supply.

The MC74VHC1GT125 input structure provides protection when voltages up to 7 V are applied, regardless of the supply voltage. This allows the MC74VHC1GT125 to be used to interface 5 V circuits to 3 V circuits. The output structures also provide protection when V_{CC} = 0 V. These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

- High Speed: t_{PD} = 3.5 ns (Typ) at V_{CC} = 5 V
- Low Power Dissipation: I_{CC} = 2 μA (Max) at T_A = 25°C
- TTL–Compatible Inputs: V_{IL} = 0.8 V; V_{IH} = 2.0 V
- CMOS–Compatible Outputs: V_{OH} > 0.8 V_{CC}; V_{OL} < 0.1 V_{CC} @Load
- Power Down Protection Provided on Inputs and Outputs
- Balanced Propagation Delays
- Pin and Function Compatible with Other Standard Logic Families
- Chip Complexity: FETs = 62; Equivalent Gates = 16

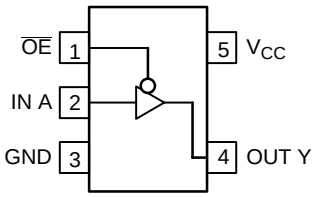

Figure 1. Pinout (Top View)

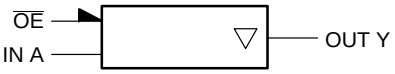

Figure 2. Logic Symbol

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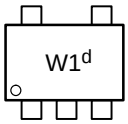
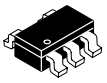
MARKING DIAGRAMS

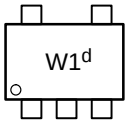
SC–88A / SOT–353/SC–70
DF SUFFIX
CASE 419A



Pin 1
d = Date Code



TSOP–5/SOT–23/SC–59
DT SUFFIX
CASE 483



Pin 1
d = Date Code

PIN ASSIGNMENT	
1	$\overline{OE}$
2	IN A
3	GND
4	OUT Y
5	V_{CC}

FUNCTION TABLE

A Input	$\overline{OE}$ Input	Y Output
L	L	L
H	L	H
X	H	Z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

April, 2001 – Rev. 5

Publication Order Number:
MC74VHC1GT125/D

MAXIMUM RATINGS (Note 1.)

Symbol	Characteristics		Value	Unit
V_{CC}	DC Supply Voltage		–0.5 to +7.0	V
V_{IN}	DC Input Voltage		–0.5 to +7.0	V
V_{OUT}	DC Output Voltage	V_{CC} = 0 High or Low State	–0.5 to 7.0 –0.5 to V_{CC} + 0.5	V
I_{IK}	Input Diode Current		–20	mA
I_{OK}	Output Diode Current	V_{OUT} < GND; V_{OUT} > V_{CC}	+20	mA
I_{OUT}	DC Output Current, per Pin		+25	mA
I_{CC}	DC Supply Current, V_{CC} and GND		+50	mA
P_D	Power dissipation in still air	SC–88A, TSOP–5	200	mW
θ_{JA}	Thermal resistance	SC–88A, TSOP–5	333	°C/W
T_L	Lead temperature, 1 mm from case for 10 s		260	°C
T_J	Junction temperature under bias		+150	°C
T_{stg}	Storage temperature		–65 to +150	°C
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 2.) Machine Model (Note 3.) Charged Device Model (Note 4.)	> 2000 > 200 N/A	V
$I_{Latch–Up}$	Latch–Up Performance	Above V_{CC} and Below GND at 125°C (Note 5.)	±500	mA

1. Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.
2. Tested to EIA/JESD22–A114–A
3. Tested to EIA/JESD22–A115–A
4. Tested to JESD22–C101–A
5. Tested to EIA/JESD78

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics		Min	Max	Unit
V_{CC}	DC Supply Voltage		3.0	5.5	V
V_{IN}	DC Input Voltage		0.0	5.5	V
V_{OUT}	DC Output Voltage		0.0	V_{CC}	V
T_A	Operating Temperature Range		–55	+125	°C
t_r , t_f	Input Rise and Fall Time	V_{CC} = 5.0 V ± 0.5 V	0	20	ns/V

DEVICE JUNCTION TEMPERATURE VERSUS TIME TO 0.1% BOND FAILURES

Junction Temperature °C	Time, Hours	Time, Years
80	1,032,200	117.8
90	419,300	47.9
100	178,700	20.4
110	79,600	9.4
120	37,000	4.2
130	17,800	2.0
140	8,900	1.0

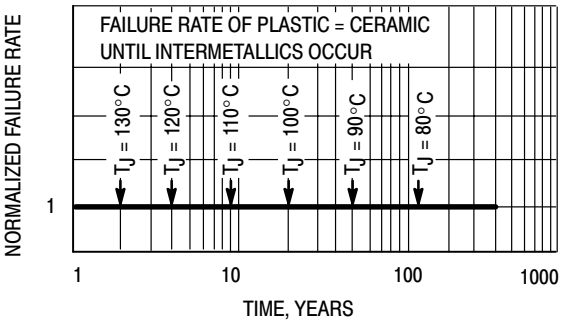


Figure 3. Failure Rate vs. Time Junction Temperature

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Conditions	V_{CC} (V)	T_A = 25°C Min	T_A = 25°C Typ	T_A = 25°C Max	$T_A \le$ 85°C Min	$T_A \le$ 85°C Max	–55 ≤ T_A ≤ 125°C Min	–55 ≤ T_A ≤ 125°C Max	Unit
V_{IH}	Minimum High–Level Input Voltage		3.0 4.5 5.5	1.4 2.0 2.0			1.4 2.0 2.0		1.4 2.0 2.0		V
V_{IL}	Maximum Low–Level Input Voltage		3.0 4.5 5.5			0.53 0.8 0.8		0.53 0.8 0.8		0.53 0.8 0.8	V
V_{OH}	Minimum High–Level Output Voltage $V_{IN} = V_{IH}$ or V_{IL}	$V_{IN} = V_{IH}$ or V_{IL} I_{OH} = – 50 μA	3.0 4.5	2.9 4.4	3.0 4.5		2.9 4.4		2.9 4.4		V
		$V_{IN} = V_{IH}$ or V_{IL} I_{OH} = – 4 mA I_{OH} = – 8 mA	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66		
V_{OL}	Maximum Low–Level Output Voltage $V_{IN} = V_{IH}$ or V_{IL}	$V_{IN} = V_{IH}$ or V_{IL} I_{OL} = 50 μA	3.0 4.5		0.0 0.0	0.1 0.1		0.1 0.1		0.1 0.1	V
		$V_{IN} = V_{IH}$ or V_{IL} I_{OL} = 4 mA I_{OL} = 8 mA	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52	
I_{IN}	Maximum Input Leakage Current	V_{IN} = 5.5 V or GND	0 to 5.5			± 0.10		± 1.0		± 1.0	μA
I_{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			2.0		20		40	μA
I_{CCT}	Quiescent Supply Current	Input: V_{IN} = 3.4 V Other Input: V_{CC} or GND	5.5			1.35		1.50		1.65	mA
I_{OPD}	Output Leakage Current	V_{OUT} = 5.5 V	0.0			0.5		5.0		10	μA
I_{OZ}	Maximum 3–State Leakage Current	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND	5.5			± 0.25		± 2.5		± 2.5	μA
I_{OPD}	Output Leakage Current	V_{OUT} = 5.5 V	0.0			0.5		5.0		10	μA

AC ELECTRICAL CHARACTERISTICS Input $t_r = t_f$ = 3.0 ns

Symbol	Parameter	Test Conditions	T_A = 25°C Min	T_A = 25°C Typ	T_A = 25°C Max	$T_A \le$ 85°C Min	$T_A \le$ 85°C Max	–55 ≤ T_A ≤ 125°C Min	–55 ≤ T_A ≤ 125°C Max	Unit
t_{PLH}, t_{PHL}	Maximum Propagation Delay, A to Y (Figures 3. and 5.)	V_{CC} = 3.3 ± 0.3 V C_L = 15pF C_L = 50pF		5.6 8.1	8.0 11.5	1.0 1.0	9.5 13.0		12.0 16.0	ns
		V_{CC} = 5.0 ± 0.5 V C_L = 15pF C_L = 50pF		3.8 5.3	5.5 7.5	1.0 1.0	6.5 8.5		8.5 10.5	
t_{PZL}, t_{PZH}	Maximum Output Enable TIme, $\overline{OE}$ to Y (Figures 4. and 5.)	V_{CC} = 3.3 ± 0.3 V C_L = 15pF $R_L = R_I$ = 500 Ω C_L = 50pF		5.4 7.9	8.0 11.5	1.0 1.0	9.5 13.0		11.5 15.0	ns
		V_{CC} = 5.0 ± 0.5 V C_L = 15pF $R_L = R_I$ = 500 Ω C_L = 50pF		3.6 5.1	5.1 7.1	1.0 1.0	6.0 8.0		7.5 9.5	
t_{PLZ}, t_{PHZ}	Maximum Output Disable Time, $\overline{OE}$ to Y (Figures 4. and 5.)	V_{CC} = 3.3 ± 0.3 V C_L = 15pF $R_L = R_I$ = 500 Ω C_L = 50pF		6.5 8.0	9.7 13.2	1.0 1.0	11.5 15.0		14.5 18.0	ns
		V_{CC} = 5.0 ± 0.5 V C_L = 15pF $R_L = R_I$ = 500 Ω C_L = 50pF		4.8 7.0	6.8 8.8	1.0 1.0	8.0 10.0		10.0 12.0	
C_{in}	Maximum Input Capacitance			4	10		10		10	pF
C_{out}	Maximum Three–State Output Capacitance (Output in High Impedance State)			6						pF

		Typical @ 25°C, V_{CC} = 5.0 V	
C_{PD}	Power Dissipation Capacitance (Note 6.)	14	pF

6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}/4$ (per buffer). C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

SWITCHING WAVEFORMS

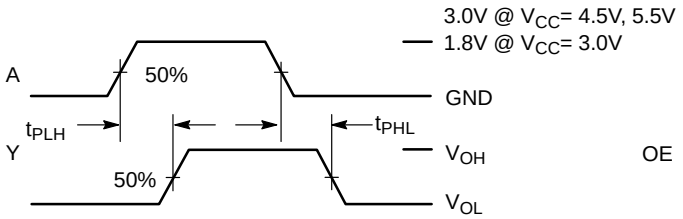


Figure 4.

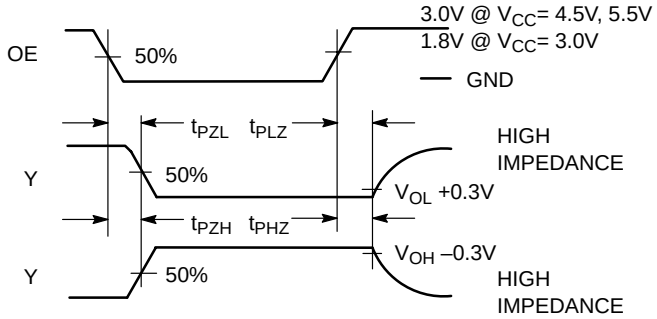
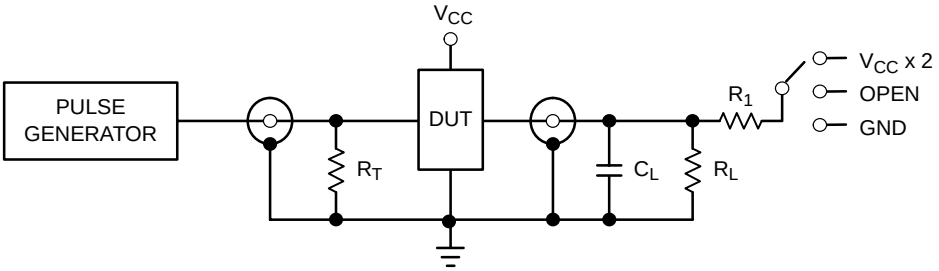


Figure 5.



TEST	SWITCH
t_{PZL}, t_{PLZ}	V_{CC} x 2
t_{PZH}, t_{PHZ}	GND
t_{PLH}, t_{PHL}	OPEN

C_L = 50 pF equivalent (Includes jig and probe capacitance) or 15 pF
$R_L = R_1$ = 500 Ω or equivalent
$R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 6. Test Circuit

DEVICE ORDERING INFORMATION

Device Order Number	Device Nomenclature						Package Type (Name/SOT#/ Common Name)	Tape and Reel Size
	Circuit Indicator	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape & Reel Suffix		
MC74VHC1GT125DF1	MC	74	VHC1G	T125	DF	1	SC–88A / SOT–353 / SC–70	178 mm (7”) 3000 Unit
MC74VHC1GT125DF2	MC	74	VHC1G	T125	DF	2	SC–88A / SOT–353 / SC–70	178 mm (7”) 3000 Unit
MC74VHC1GT125DF4	MC	74	VHC1G	T125	DF	4	SC–88A / SOT–353 / SC–70	330 mm (13”) 10,000 Unit
MC74VHC1GT125DT1	MC	74	VHC1G	T125	DT	1	TSOPS / SOT–23 / SC–59	178 mm (7”) 3000 Unit
MC74VHC1GT125DT3	MC	74	VHC1G	T125	DT	3	TSOPS / SOT–23 / SC–59	330 mm (13”) 10,000 Unit

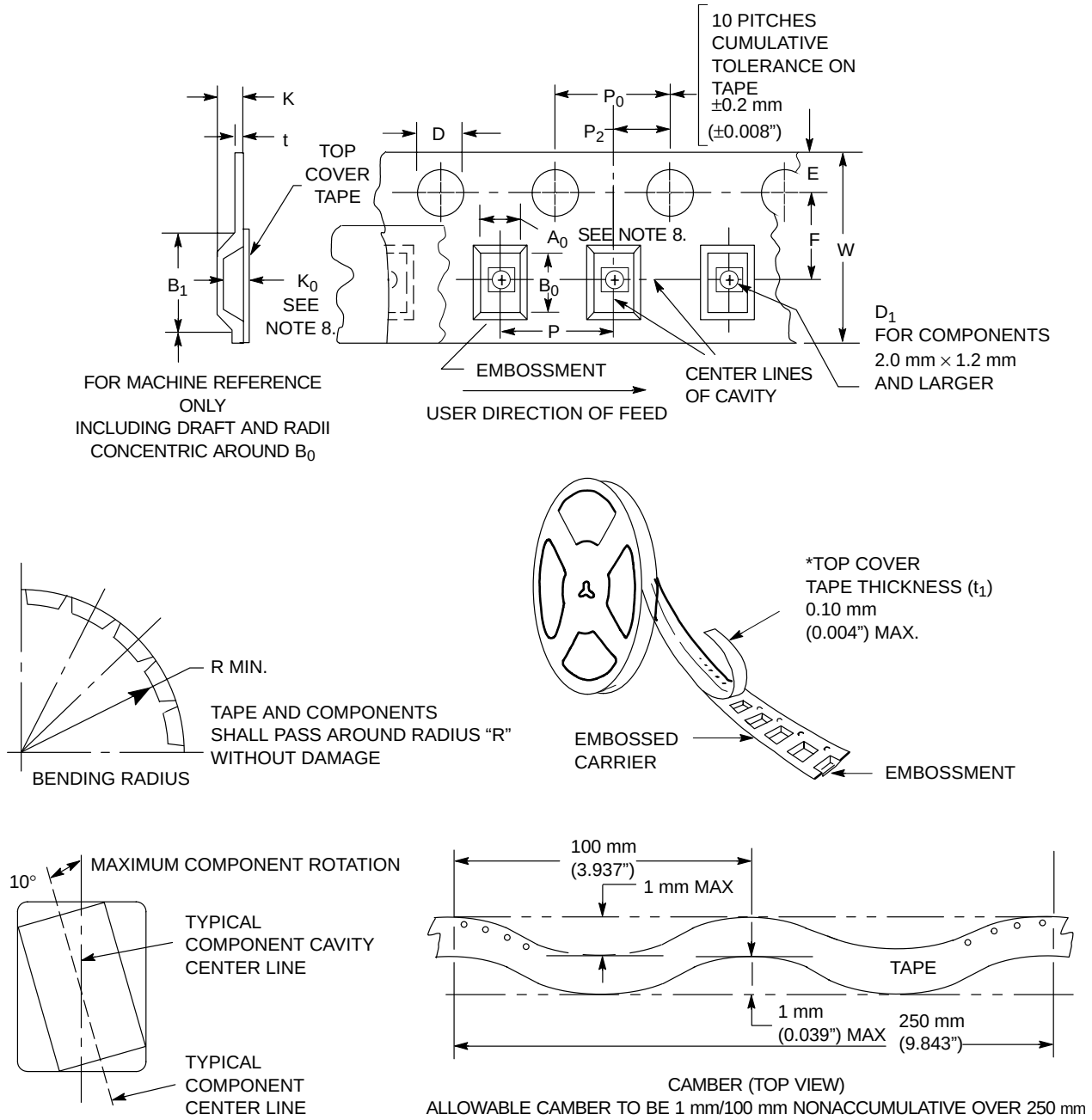


Figure 7. Carrier Tape Specifications

EMBOSSED CARRIER DIMENSIONS (See Notes 7. and 8.)

Tape Size	B_1 Max	D	D_1	E	F	K	P	P_0	P_2	R	T	W
8 mm	4.35 mm (0.171")	1.5 +0.1/ –0.0 mm (0.059 +0.004/ –0.0")	1.0 mm Min (0.039")	1.75 ±0.1 mm (0.069 ±0.004")	3.5 ±0.5 mm (1.38 ±0.002")	2.4 mm (0.094")	4.0 ±0.10 mm (0.157 ±0.004")	4.0 ±0.1 mm (0.156 ±0.004")	2.0 ±0.1 mm (0.079 ±0.002")	25 mm (0.98")	0.3 ±0.05 mm (0.01 +0.0038/ –0.0002")	8.0 ±0.3 mm (0.315 ±0.012")

7. Metric Dimensions Govern–English are in parentheses for reference only.
8. A_0, B_0, and K_0 are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

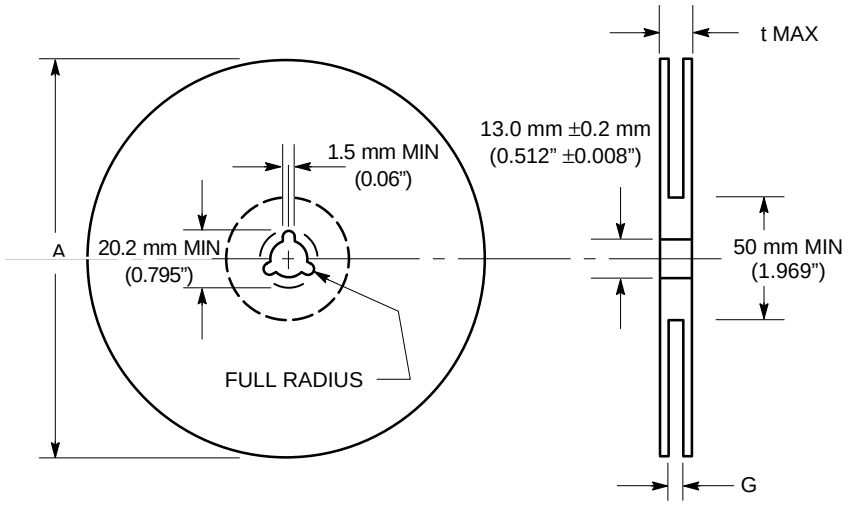


Figure 8. Reel Dimensions

REEL DIMENSIONS

Tape Size	T&R Suffix	A Max	G	t Max
8 mm	T1, T2	178 mm (7”)	8.4 mm, +1.5 mm, –0.0 (0.33” + 0.059”, –0.00)	14.4 mm (0.56”)
8 mm	T3, T4	330 mm (13”)	8.4 mm, +1.5 mm, –0.0 (0.33” + 0.059”, –0.00)	14.4 mm (0.56”)

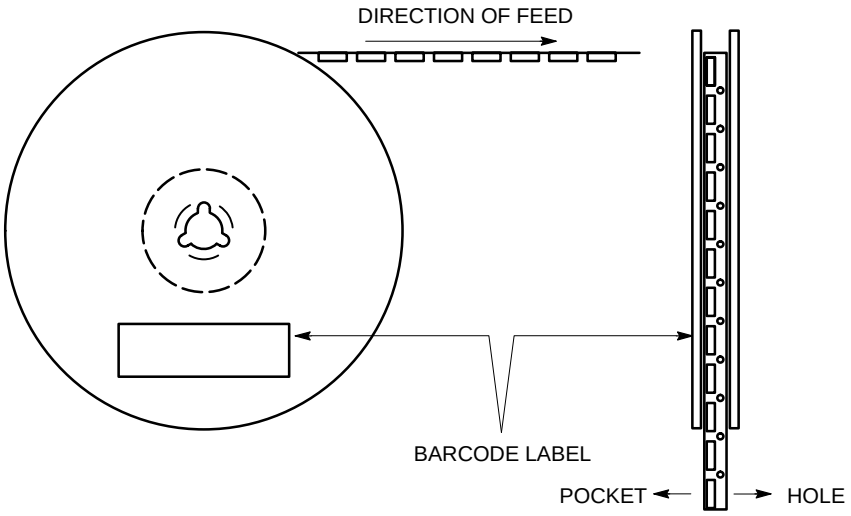


Figure 9. Reel Winding Direction

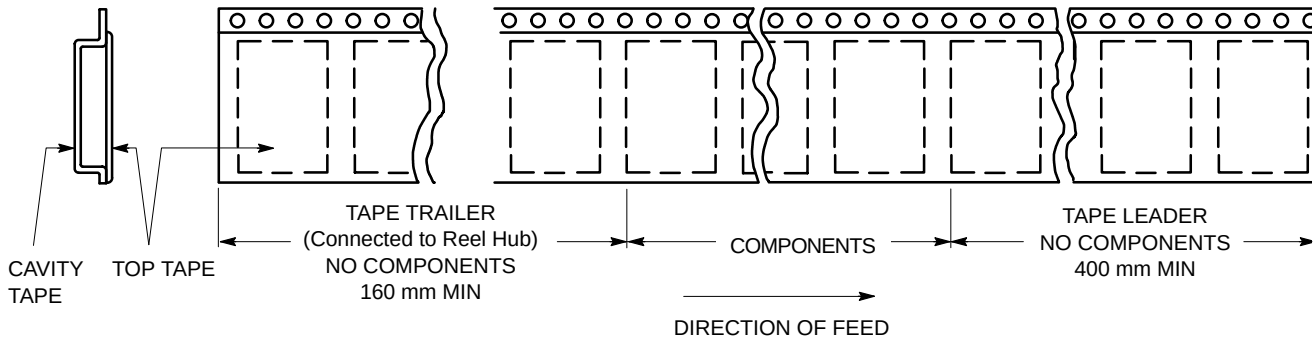


Figure 10. Tape Ends for Finished Goods

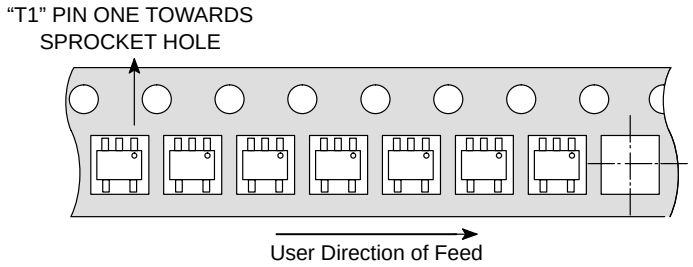


Figure 11. DF1 (SC88A) Reel Configuration/Orientation

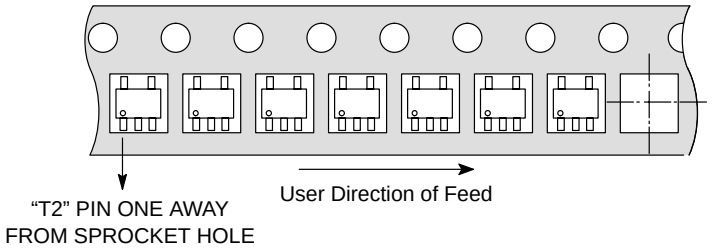


Figure 12. DF2 and DF4 (SC88A) Reel Configuration/Orientation

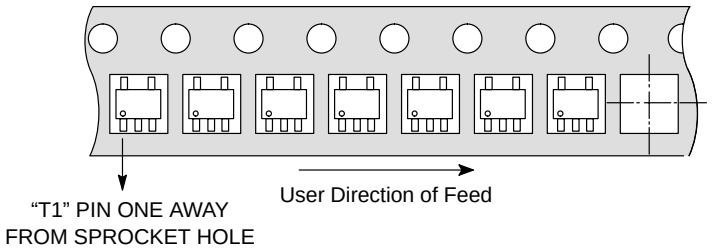
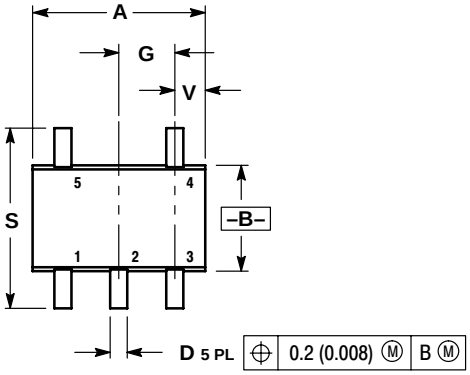


Figure 13. DT1 and DT3 (TSOP5) Reel Configuration/Orientation

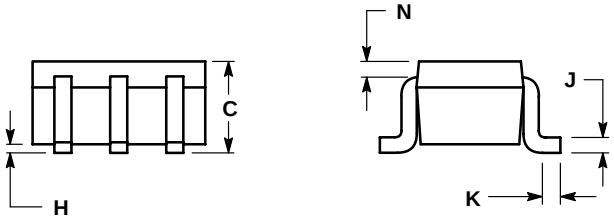
PACKAGE DIMENSIONS

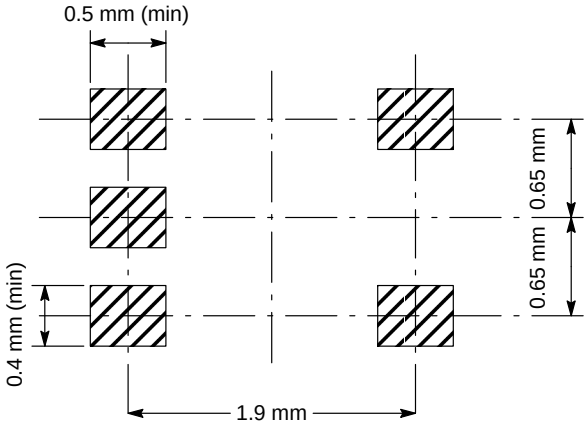
SC−88A / SOT−353 / SC−70
DF SUFFIX
5−LEAD PACKAGE
CASE 419A−01
ISSUE E



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

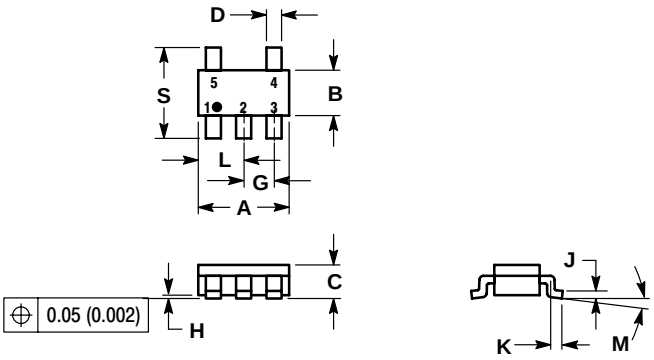
DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20
V	0.012	0.016	0.30	0.40





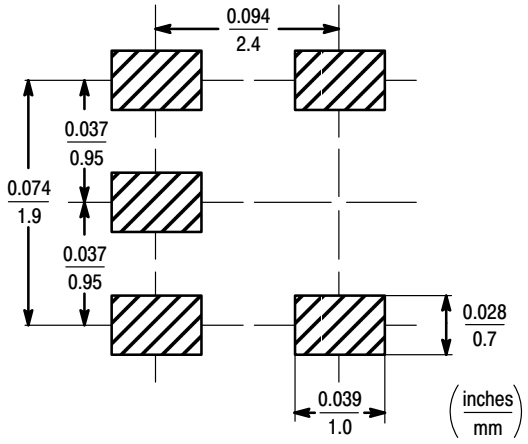
PACKAGE DIMENSIONS

TSOP–5 / SOT–23 / SC–59
DT SUFFIX
5–LEAD PACKAGE
CASE 483–01
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	2.90	3.10	0.1142	0.1220
B	1.30	1.70	0.0512	0.0669
C	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.00	0.0335	0.0413
H	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
K	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
M	0°	10°	0°	10°
S	2.50	3.00	0.0985	0.1181



Notes

Notes

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